



## ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

Title of Invention	POWER SUPPLY AND TRANSFORMER
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Application Number: 10/737333



Confirmation Number: 7566

First Named Applicant: Stephen P. Goldschmidt

Attorney Docket Number: 9501-73714

Art Unit: 2838

Search string: ( 5409784 or 5425332 or 5437250 or 5887554  
or 20030143442 or 20030143445 or  
20030140622 ).pn.

### US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
1	1	5409784	1995-04-25	Bromberg et al.			
1	2	5425332	1995-06-20	Rabinovich et al.			
1	3	5437250	1995-08-01	Rabinovich et al.			
1	4	5887554	1999-03-30	Cohn et al.			

### US Published Applications

Note: Applicant is not required to submit a paper copy of cited US Published Applications

init	Cite.No.	Pub. No.	Date	Applicant	Kind	Class	Subclass
1	1	20030143442	2003-07-31	Daniel et al.			
1	2	20030143445	2003-07-31	Daniel et al.			
1	3	20030140622	2000-07-31	Taylor, III et al.			

### Signature

Examiner Name	Date
BINH Q. TRAN	7/1/05



U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICE  
INFORMATION DISCLOSURE STATEMENT

ATTY. DOCKET NO.  
9501-73714

SERIAL NO.  
10/737,333

APPLICANT  
Stephen P. Goldschmidt, et al.

FILING DATE  
December 16, 2003

GROUP  
Unknown 3748

## U.S. PATENT DOCUMENTS

*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date if Appropriate
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

## FOREIGN PATENT DOCUMENTS

		Document Number	Date	Country	Class	Subclass	Translation Yes No
	AL						
	AM						
	AN						
	AO						
	AP						

## OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

<i>BS</i>	AR	Bill Andreyak, "New Driver ICs Optimize High Speed Power MOSFET Switching Characteristics," pp. 3-151 to 3-165, 5 September 1999.
<i>BS</i>	AS	Phillips Semiconductors Product Specification for Insulated Gate Bipolar Transistor (IGBT) BUK854-800A , pp. 1 to 7, October 1994.
	AT	
	AU	
	AV	
	AW	
	AX	
	AY	
	AZ	

Examiner

*BINH TRAN*

Date Considered

*7/1/05*

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609.

Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.